



MODULATOR



The MXAN-LN series are high bandwidth intensity modulators specially designed for the transmission of analog signals over optical fibers.

The MXAN-LN's performance parameters meet the requirement of the most demanding analog transmission links for military and civil applications: the x-cut design offers an unmatched stability, the low insertion loss optimizes links gain and the high linearity preserves the signal quality. They are specially suitable for microwave links and remoted antennas.

#### **FEATURES**

- · High linearity
- · Bandwidth 10 GHz, 20 GHz, 40 GHz
- · High stability
- · Low insertion loss
- Operation in C and L bands

#### **APPLICATIONS**

- RoF
- Antenna remoting
- · Microwave and Radar links
- Space and defence systems

#### **OPTIONS**

- 1300 nm, 1000 nm, 800 nm versions
- Hermetic sealing
- · Space qualified

#### **RELATED EQUIPMENTS**

- DR-AN RF amplifiers
- MBC ditherless Bias Controllers
- Turn-key ModBox systems

## MXAN-LN-10 Performance Highlights

Parameter	Min	Тур	Max	Unit
Operating wavelength	1530	-	1625	nm
Insertion loss	-	3.5	-	dB
Insertion loss (with low IL option)	-	2.7	3	dB
Electro-optical bandwidth	10	12	-	GHz
Vπ RF @50 kHz	-	5.5	-	V

Specifications given at 25 °C, 50  $\Omega$ , 1550 nm

#### MXAN-LN-20 Performance Highlights

Parameter	Min	Тур	Max	Unit
Operating wavelength	1530	-	1625	nm
Insertion loss	-	3.5	-	dB
Electro-optical bandwidth	20	25	-	GHz
Vπ RF @50 kHz	-	5	-	V
2 <sup>nd</sup> harmonic suppression ratio	-	60	-	dB

Specifications given at 25 °C, 50  $\Omega$ , 1550 nm

### MXAN-LN-40 Performance Highlights

Parameter	Min	Тур	Max	Unit
Operating wavelength	1530	-	1625	nm
Insertion loss	-	3.5	-	dB
Electro-optical bandwidth	28	30	-	GHz
Vπ RF @50 kHz	-	5	-	V
2 <sup>nd</sup> harmonic suppression ratio	-	60	-	dB

Specifications given at 25 °C, 50  $\Omega$ , 1550 nm



**M**ODULATOR

# MXAN-LN-10

10 GHz Analog Intensity Modulator

### **Electrical Characteristics**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Electro-optic bandwidth	S <sub>21</sub>	RF electrodes, from 2 GHz	10	12	-	GHz
Ripple S <sub>21</sub>	ΔS <sub>21</sub>	RF electrodes, f < 10 GHz	-	0.5	1	dB
Electrical return loss	S <sub>11</sub>	RF electrodes, f < 10 GHz	-	-12	-10	dB
Vπ RF @50 kHz	VπRF <sub>50 kHz</sub>	RF electrodes	-	5.5	6	V
Vπ RF @10 GHz	VπRF <sub>10 GHz</sub>	RF electrodes	-	6.5	7	V
Vp DC electrodes	VπDC	DC electrodes	-	6.5	7	V
2 <sup>nd</sup> harmonic suppression ratio	H <sub>1</sub> - H <sub>2</sub>	Measured @5 GHz	-	70	-	dB
Input 3 <sup>rd</sup> order intercept	IIP3	Measured @5 GHz	28	30	-	dBm
RF input impedance	Z <sub>in-RF</sub>	-	-	50	-	Ω
DC input impedance	Z <sub>in-DC</sub>	-	-	1	-	ΜΩ

 $50\,\Omega$  RF input

## **Optical Characteristics**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Crystal	-	-		Lithium Niobate X-Cut Y-Prop		
Operating wavelength	λ	-	1530	1550	1625	nm
Insertion loss	IL	Without connectors	-	3.5	-	dB
Insertion loss (with low IL option)	LIL	Without connectors	-	2.7	3	dB
DC extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	22	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	α	-	-0.1	0	0.1	-

All specifications given at 25°C, 1550 nm, unless differently specified

#### **Absolute Maximum Ratings**

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit
RF input power	EP <sub>in</sub>	-	28	dBm
Bias voltage	V <sub>bias</sub>	-20	+20	V
Optical input power	OP <sub>in</sub>	-	20	dBm
Operating temperature	ОТ	0	+70	°C
Storage temperature	ST	-40	+85	°C



**M**ODULATOR

# MXAN-LN-20

20 GHz Analog Intensity Modulator

#### **Electrical Characteristics**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Electro-optic bandwidth	S <sub>21</sub>	RF electrodes, from 2 GHz	20	25	-	GHz
Ripple S <sub>21</sub>	ΔS <sub>21</sub>	RF electrodes, f < 20 GHz	-	0.5	1	dB
Electrical return loss	S <sub>11</sub>	RF electrodes, f < 20 GHz	-	-12	-10	dB
Vπ RF @50 kHz	VπRF <sub>50 kHz</sub>	RF electrodes	-	5	5.5	V
Vπ RF @20 GHz	VπRF <sub>20 GHz</sub>	RF electrodes	-	7	8	V
$V\pi$ DC electrodes	VπDC	DC electrodes	-	6.5	7	V
2 <sup>nd</sup> harmonic suppression ratio	H <sub>1</sub> -H <sub>2</sub>	Measured @5 GHz, RF <sub>IN</sub> = 0 dBm	-	60	-	dB
Input 3 <sup>rd</sup> order intercept	IIP3	Measured @5 GHz	28	30	-	dBm
RF input impedance	Z <sub>in-RF</sub>	-	-	50	-	Ω
DC input impedance	Z <sub>in-DC</sub>	-	-	1	-	ΜΩ

 $50\,\Omega$  RF input

## **Optical Characteristics**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Crystal	-	-	Lithium Niobate X-Cut Y-Prop			
Operating wavelength	λ	-	1530	1550	1625	nm
Insertion loss	IL	Without connectors	-	3.5	4.5	dB
DC extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	25	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	α	-	-0.1	0	0.1	-

All specifications given at 25°C, 1550 nm, unless differently specified

## **Absolute Maximum Ratings**

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Parameter	Symbol	Min	Max	Unit
RF input power	EP <sub>in</sub>	-	28	dBm
Bias voltage	V <sub>bias</sub>	-20	+20	V
Optical input power	OP <sub>in</sub>	-	20	dBm
Operating temperature	ОТ	0	+70	°C
Storage temperature	ST	-40	+85	°C



**M**ODULATOR

# MXAN-LN-40

40 GHz Analog Intensity Modulator

### **Electrical Characteristics**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Electro-optic bandwidth	S <sub>21</sub>	RF electrodes, from 2 GHz	28	30	-	GHz
Ripple S <sub>21</sub>	ΔS <sub>21</sub>	RF electrodes, f < 30 GHz	-	0.5	1	dB
Electrical return loss	S <sub>11</sub>	RF electrodes, f < 30 GHz	-	-12	-10	dB
Vπ RF @50 kHz	VπRF <sub>50 kHz</sub>	RF electrodes	-	5	6	V
Vπ RF @20 GHz	VπRF <sub>20 GHz</sub>	RF electrodes	-	7	8	V
$V\pi$ DC electrodes	VπDC	DC electrodes	-	6.5	7	V
2 <sup>nd</sup> harmonic suppression ratio	H <sub>1</sub> -H <sub>2</sub>	Measured @5 GHz, RF <sub>IN</sub> = 0 dBm	-	60	-	dB
Input 3 <sup>rd</sup> order intercept	IIP3	Measured @5 GHz	28	30	-	dBm
RF input impedance	Z <sub>in-RF</sub>	-	-	50	-	Ω
DC input impedance	Z <sub>in-DC</sub>	-	-	1	-	MΩ

 $50\,\Omega$  RF input

## **Optical Characteristics**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Crystal	-	-	Lithium Niobate X-Cut Y-Prop			
Operating wavelength	λ	-	1530	1550	1625	nm
Insertion loss	IL	Without connectors	-	3.5	4.5	dB
DC extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	25	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	α	-	-0.1	0	0.1	-

All specifications given at 25 °C, 1550 nm, unless differently specified

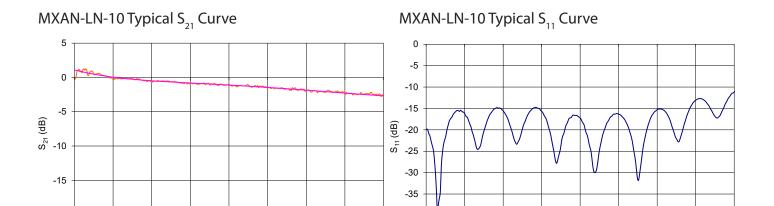
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Parameter	Symbol	Min	Max	Unit
RF input power	EP <sub>in</sub>	-	28	dBm
Bias voltage	V <sub>bias</sub>	-20	+20	V
Optical input power	OP <sub>in</sub>	-	20	dBm
Operating temperature	ОТ	0	+70	°C
Storage temperature	ST	-40	+85	°C



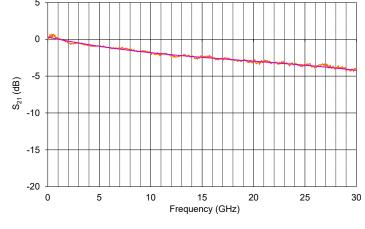
# **M**ODULATOR



16

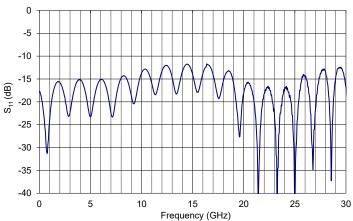
# MXAN-LN-20 Typical S<sub>21</sub> Curve

-20



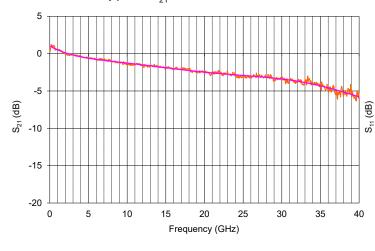
Frequency (GHz)

# MXAN-LN-20 Typical $S_{11}$ Curve

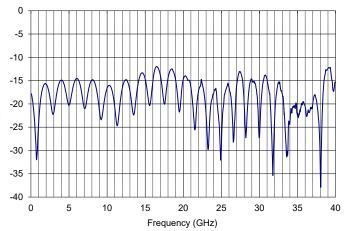


Frequency (GHz)

MXAN-LN-40 Typical S<sub>21</sub> Curve

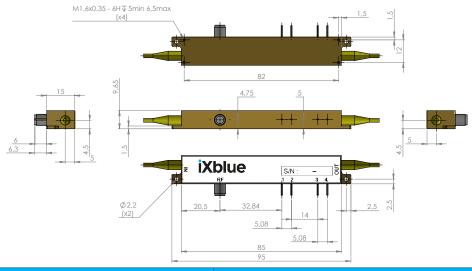


# MXAN-LN-40 Typical S<sub>11</sub> Curve



# Mechanical Diagram and Pinout

All measurements in mm



Port	Function	Note
IN	Optical input port	Polarization maintaining fiber, Corning PM 15-U25D, Length 1.5 meter. Buffer diameter 900 mm
OUT	Optical output port	Polarization maintaining fiber, Corning PM 15-U25D, Length 1.5 meter. Buffer diameter 900 mm
RF	RF input port	MX-LN-10: Wiltron female K (SMA compatible) MX-LN-20: Wiltron female K or V (optional) MX-LN-40: Wiltron female V
1	Ground	Pin feed through diameter 1.0 mm
2	DC	Pin feed through diameter 1.0 mm
3, 4	Photodiode cathode, anode	Pin feed through diameter 1.0 mm

## Ordering information

### MXAN-LN-BW-XX-Y-Z-AB-CD-LIL

BW = Bandwidth: 10 10 GHz 20 20 GHz 40 40 GHz

XX = Internal photodiode: 00 Not integrated PD PD Integrated

Y = Input fiber: P Polarization maintaining S Standard single mode

Z = Output fiber: P Polarization maintaining S Standard single mode

AB = Input connector: 00 bare fiber FA FC/APC FC FC/SPC

CD = Output connector: 00 bare fiber FA FC/APC FC FC/SPC

LIL = Low Insertion Loss option for the MXAN-LN-10 only

Note: optical connectors are Seikoh-Giken with narrow key or equivalent

## About us

iXblue Photonics includes iXblue iXFiber brand that produces specialty optical fibers and Bragg gratings based fiber optics components and iXblue Photline brand that provides optical modulation solutions based on the company lithium niobate (LiNbO<sub>2</sub>) modulators and RF electronic modules.

iXblue Photonics serves a wide range of industries: sensing and instruments, defense, telecommunications, space and fiber lasers as well as research laboratories all over the world.

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